Internally Trimmed Precision IC Multiplier

AD632

FEATURES

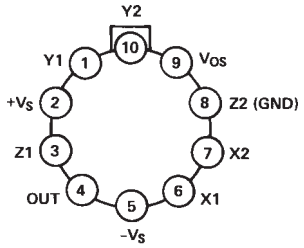
Pretrimmed to ±0.5% Max 4-Quadrant Error
All Inputs (X, Y and Z) Differential, High Impedance for $[(X_1–X_2)(Y_1–Y_2)/10] + Z_2$ Transfer Function
Scale-Factor Adjustable to Provide up to X10 Gain
Low Noise Design: 90 μV rms, 10 Hz–10 kHz
Low Cost, Monolithic Construction
Excellent Long-Term Stability

APPLICATIONS

High Quality Analog Signal Processing
Differential Ratio and Percentage Computations
Algebraic and Trigonometric Function Synthesis
Accurate Voltage Controlled Oscillators and Filters

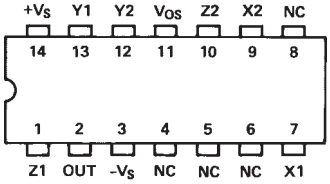
PIN CONFIGURATIONS

H-Package TO-100



TOP VIEW

D-Package TO-116



TOP VIEW

PRODUCT DESCRIPTION

The AD632 is an internally-trimmed monolithic four-quadrant multiplier/divider. The AD632B has a maximum multiplying error of ±0.5% without external trims.

Excellent supply rejection, low temperature coefficients and long term stability of the on-chip thin film resistors and buried zener reference preserve accuracy even under adverse conditions. The simplicity and flexibility of use provide an attractive alternative approach to the solution of complex control functions.

The AD632 is pin-for-pin compatible with the industry standard AD532 with improved specifications and a fully differential high impedance Z-input. The AD632 is capable of providing gains of up to X10, frequently eliminating the need for separate instrumentation amplifiers to precondition the inputs. The AD632 can be effectively employed as a variable gain differential input amplifier with high common-mode rejection. The effectiveness of the variable gain capability is enhanced by the inherent low noise of the AD632: 90 μV rms.

PRODUCT HIGHLIGHTS

Guaranteed Performance Over Temperature

The AD632A and AD632B are specified for maximum multiplying errors of ±1.0% and ±0.5% of full scale, respectively at +25°C and are rated for operation from –25°C to +85°C. Maximum multiplying errors of ±2.0% (AD632S) and ±1.0% (AD632T) are guaranteed over the extended temperature range of –55°C to +125°C.

High Reliability

The AD632S and AD632T series are also available with MIL-STD-883 Level B screening and all devices are available in either the hermetically-sealed TO-100 metal can or TO-116 ceramic DIP package.

REV. A

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AD632–SPECIFICATIONS (@ +25°C, V_S = ±15 V, R ≥ 2 kΩ unless otherwise noted)

Model	AD632A Min	AD632A Typ	AD632A Max	AD632B Min	AD632B Typ	AD632B Max	AD632S Min	AD632S Typ	AD632S Max	AD632T Min	AD632T Typ	AD632T Max	Units
MULTIPLIER PERFORMANCE													
Transfer Function	$\frac{(X_1-X_2)(Y_1-Y_2)}{10V}+Z_2$			$\frac{(X_1-X_2)(Y_1-Y_2)}{10V}+Z_2$			$\frac{(X_1-X_2)(Y_1-Y_2)}{10V}+Z_2$			$\frac{(X_1-X_2)(Y_1-Y_2)}{10V}+Z_2$			
Total Error[1] (–10 V ≤ X, Y ≤ +10 V)			**±1.0**			**±0.5**			**±1.0**			**±0.5**	%
T_A = Min to Max		**±1.5**			**±1.0**			**±2.0**			**±1.0**		%
Total Error vs. Temperature		±0.022			±0.015			**±0.02**			**±0.01**		%/°C
Scale Factor Error (SF = 10.000 V Nominal)[2]		±0.25			±0.1			±0.25			±0.1		%
Temperature-Coefficient of Scaling-Voltage		±0.02			**±0.01**			±0.2				**±0.005**	%/°C
Supply Rejection (±15 V ± 1 V)		±0.01			±0.01			±0.01			±0.01		%
Nonlinearity, X (X = 20 V p-p, Y = 10 V)		±0.4			±0.2	±0.3		±0.4			±0.2	±0.3	%
Nonlinearity, Y (Y = 20 V p-p, X = 10 V)		±0.2			±0.1	±0.1		±0.2			±0.1	±0.1	%
Feedthrough[3], X (Y Nulled, X = 20 V p-p 50 Hz)		±0.3			±0.15	±0.3		±0.3			±0.15	±0.3	%
Feedthrough[3], Y (X Nulled, Y = 20 V p-p 50 Hz)		±0.01			±0.01	±0.1		±0.01			±0.01	±0.1	%
Output Offset Voltage		±5	**±30**		±2	±15		±5	**±30**		±2	±15	mV
Output Offset Voltage Drift		200			100				**500**			**300**	µV/°C
DYNAMICS													
Small Signal BW, (V_{OUT} = 0.1 rms)		1			1			1			1		MHz
1% Amplitude Error (C_{LOAD} = 1000 pF)		50			50			50			50		kHz
Slew Rate (V_{OUT} 20 p-p)		20			20			20			20		V/µs
Settling Time (to 1%, ΔV_{OUT} = 20 V)		2			2			2			2		µs
NOISE													
Noise Spectral-Density SF = 10 V		0.8			0.8			0.8			0.8		µV/√Hz
SF = 3 V[4]		0.4			0.4			0.4			0.4		µV/√Hz
Wideband Noise A = 10 Hz to 5 MHz		1.0			1 .0			1.0			1.0		mV rms
P = 10 Hz to 10 kHz		90			90			90			90		µV/rms
OUTPUT													
Output Voltage Swing	**±11**			**±11**			**±11**			**±11**			V
Output Impedance (f ≤ 1 kHz)		0.1			0.1			0.1			0.1		Ω
Output Short Circuit Current (R_L = 0, T_A = Min to Max)		30			30			30			30		mA
Amplifier Open Loop Gain (f = 50 Hz)		70			70			70			70		dB
INPUT AMPLIFIERS (X, Y and Z)[5]													
Signal Voltage Range (Diff. or CM		±10			±10			±10			±10		V
Operating Diff.)		±12			±12			±12			±12		V
Offset Voltage X, Y		±5	**±20**		±2	**±10**		±5	**±20**		±2	**±10**	mV
Offset Voltage Drift X, Y		100			50			100			150		µV/°C
Offset Voltage Z		±5	**±30**		±2	**±15**		±5	**±30**		±2	**±15**	mV
Offset Voltage Drift Z		200			100				500			300	µV/°C
CMRR	**60**	80		**70**	90		**60**	80		**70**	90		dB
Bias Current		0.8	**2.0**		0.8	**2.0**		0.8	**2.0**		0.8	**2.0**	µA
Offset Current		0.1			0. I			0.1			0.1		µA
Differential Resistance		10			10			1 0			10		MΩ
DIVIDER PERFORMANCE													
Transfer Function ($X_1 > X_2$)	$10V\frac{(Z_2-Z_1)}{(X_1-X_2)}+Y_1$			$10V\frac{(Z_2-Z_1)}{(X_1-X_2)}+Y_1$			$10V\frac{(Z_2-Z_1)}{(X_1-X_2)}+Y_1$			$10V\frac{(Z_2-Z_1)}{(X_1-X_2)}+Y_1$			
Total Error[1]													
(X = 10 V, –10 V ≤ Z ≤ +10 V)		±0.75			±0.35			±0.75			±0.35		%
(X = 1 V, –1 V ≤ Z ≤ +1 V)		±2.0			±1.0			±2.0			±1.0		%
(0.1 V ≤ X ≤ 10 V, –10 V ≤ Z ≤ 10 V)		±2.5			±1.0			±2.5			±1.0		%
SQUARER PERFORMANCE													
Transfer Function	$\frac{(X_1-X_2)^2}{10V}+Z_2$			$\frac{(X_1-X_2)^2}{10V}+Z_2$			$\frac{(X_1-X_2)^2}{10V}+Z_2$			$\frac{(X_1-X_2)^2}{10V}+Z_2$			
Total Error (–10 V ≤ X ≤ 10 V)		±0.6			±0.3			±0.6			±0.3		%
SQUARE-ROOTER PERFORMANCE													
Transfer Function, ($Z_1 \le Z_2$)	$\sqrt{10V(Z_2-Z_1)+X_2}$			$\sqrt{10V(Z_2-Z_1)+X_2}$			$\sqrt{10V(Z_2-Z_1)+X_2}$			$\sqrt{10V(Z_2-Z_1)+X_2}$			
Total Error[1] (1 V ≤ Z ≤ 10 V)		±1.0			±0.5			±1.0			±0.5		%

Model	AD632A Min	AD632A Typ	AD632A Max	AD632B Min	AD632B Typ	AD632B Max	AD632S Min	AD632S Typ	AD632S Max	AD632T Min	AD632T Typ	AD632T Max	Units
POWER SUPPLY SPECIFICATIONS													
Supply Voltage													
Rated Performance		±15			±15			±15			±15		V
Operating	±8		**±18**	±8		**±18**	±8		**±22**	±8		**±22**	V
Supply Current													
Quiescent		4	**6**		4	6		4	**6**		4	6	mA

NOTES
[1]Figures given are percent of full-scale, ±10 V (i.e., 0.01% = 1 mV).
[2]May be reduced to 3 V using external resistor between $-V_S$ and SF.
[3]Irreducible component due to nonlinearity: excludes effect of offsets.
[4]Using external resistor adjusted to give SF = 3 V.
[5]See functional block diagram for definition of sections.

All min and max specifications are guaranteed.
Specifications shown in **boldface** are tested on all production units at final electrical test. Results from those tests are used to calculate outgoing quality levels.
Specifications subject to change without notice.

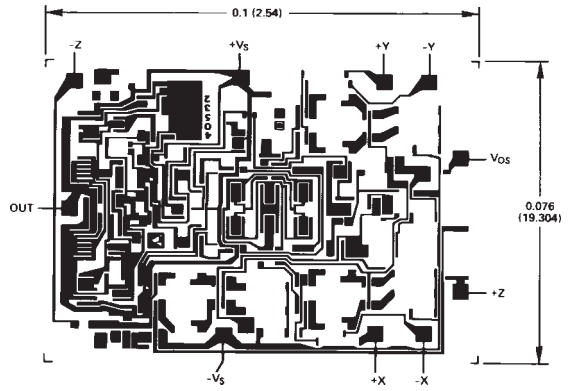
ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option*
AD632AD	–25°C to +85°C	Side Brazed Ceramic DIP	D-14
AD632BD	–25°C to +85°C	Side Brazed Ceramic DIP	D-14
AD632AH	–25°C to +85°C	Header	H-10A
AD632BH	–25°C to +85°C	Header	H-10A
AD632SD	–55°C to +125°C	Side Brazed Ceramic DIP	D-14
AD632SD/833B	–55°C to +125°C	Side Brazed Ceramic DIP	D-14
AD632TD	–55°C to +125°C	Side Brazed Ceramic DIP	D-14
AD632TD/883B	–55°C to +125°C	Side Brazed Ceramic DIP	D-14
AD632SH	–55°C to +125°C	Header	H-10A
AD632SH/883B	–55°C to +125°C	Header	H-10A
AD632TH	–55°C to +125°C	Header	H-10A
AD632TH/883B	–55°C to +125°C	Header	H-10A

*For outline information see Package Information section.

CHIP DIMENSIONS AND PAD LAYOUT

Dimensions shown in inches and (mm).
(Contact factory for latest dimensions.)



For further information, consult factory.

Thermal Characteristics

Thermal Resistance	θ_{JC} = 25°C/W for H-10A θ_{JA} = 150°C/W for H-10A θ_{JC} = 25°C/W for D-14 θ_{JA} = 95°C/W for D-14

Typical Performance Curves

(typical @ +25°C with $\pm V_S$ = 15 V)

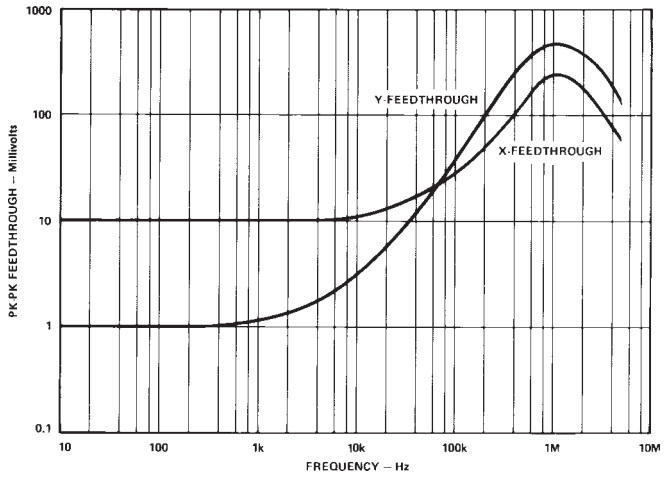


Figure 1. AC Feedthrough vs. Frequency

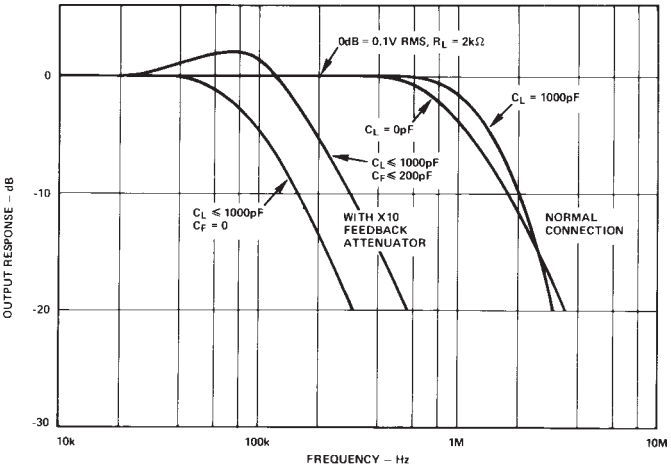


Figure 2. Frequency Response as a Multiplier

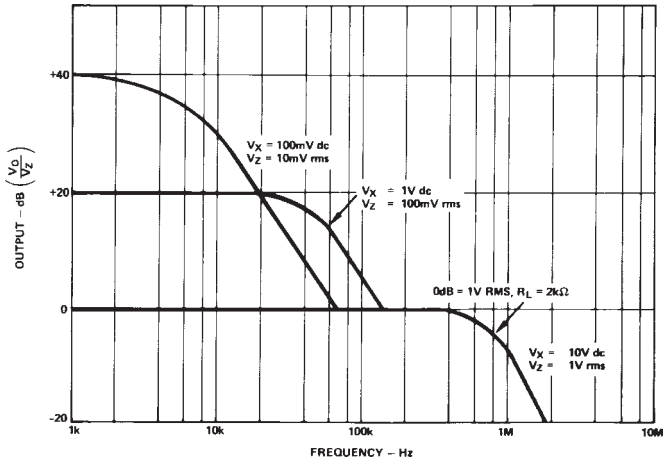


Figure 3. Frequency Response vs. Divider Denominator Input Voltage

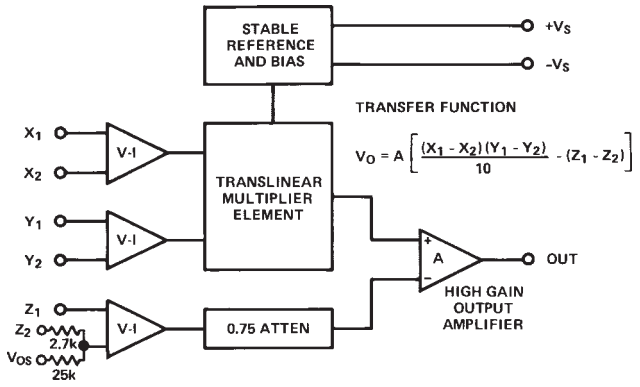


Figure 4. AD632 Functional Block Diagram

OPERATION AS A MULTIPLIER

Figure 5 shows the basic connection for multiplication. Note that the circuit will meet all specifications without trimming.

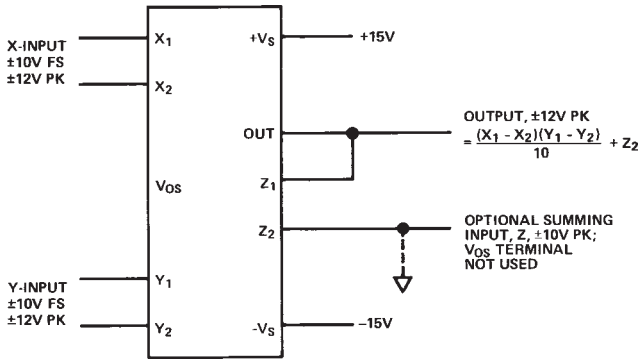


Figure 5. Basic Multiplier Connection

In some cases the user may wish to reduce ac feedthrough to a minimum (as in a suppressed carrier modulator) by applying an external trim voltage (±30 mV range required) to the X or Y input. Curve 1 shows the typical ac feedthrough with this adjustment mode. Note that the feedthrough of the Y input is a factor of 10 lower than that of the X input and should be used in applications where null suppression is critical.

The Z_2 terminal of the AD632 may be used to sum an additional signal into the output. In this mode the output amplifier behaves as a voltage follower with a 1 MHz small signal bandwidth and a 20 V/μs slew rate. This terminal should always be referenced to the ground point of the driven system, particularly if this is remote. Likewise the differential inputs should be referenced to their respective signal common potentials to realize the full accuracy of the AD632.

A much lower scaling voltage can be achieved without any reduction of input signal range using a feedback attenuator as shown in Figure 6. In this example, the scale is such that $V_{OUT} = XY$, so that the circuit can exhibit a maximum gain of 10. This connection results in a reduction of bandwidth to about 80 kHz without the peaking capacitor C_F. In addition, the output offset voltage is increased by a factor of 10 making external adjustments necessary in some applications.

Feedback attenuation also retains the capability for adding a signal to the output. Signals may be applied to the Z terminal, where they are amplified by –10, or to the common ground connection where they are amplified by –1. Input signals may also be applied to the lower end of the 2.7 kΩ resistor, giving a gain of +9.

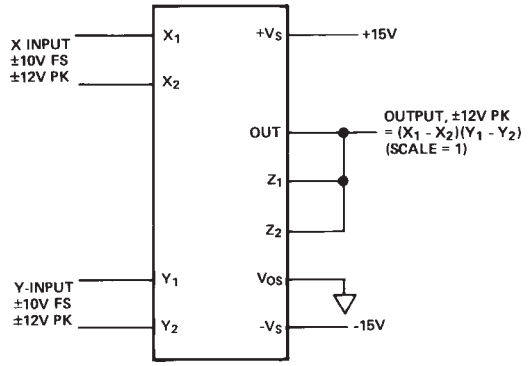


Figure 6. Connections for Scale-Factor of Unity

OPERATION AS A DIVIDER

Figure 7 shows the connection required for division. Unlike earlier products, the AD632 provides differential operation on both numerator and denominator, allowing the ratio of two floating variables to be generated. Further flexibility results from access to a high impedance summing input to Y_1. As with all dividers based on the use of a multiplier in a feedback loop, the bandwidth is proportional to the denominator magnitude, as shown in Figure 3.

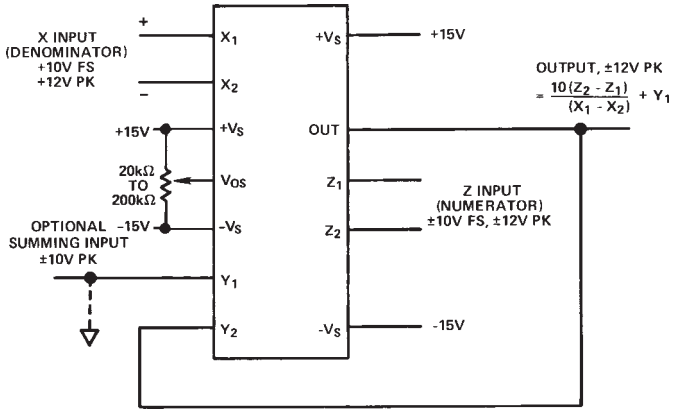


Figure 7. Basic Divider Connection

Without additional trimming, the accuracy of the AD632B is sufficient to maintain a 1% error over a 10 V to 1 V denominator range (The AD535 is functionally equivalent to the AD632 and has guaranteed performance in the divider and square-rooter configurations and is recommended for such applications).

This range may be extended to 100:1 by simply reducing the X offset with an externally generated trim voltage (range required is ±3.5 mV max) applied to the unused X input. To trim, apply a ramp of +100 mV to +V at 100 Hz to both X_1 and Z_1 (if X_2 is used for offset adjustment, otherwise reverse the signal polarity) and adjust the trim voltage to minimize the variation in the output.*

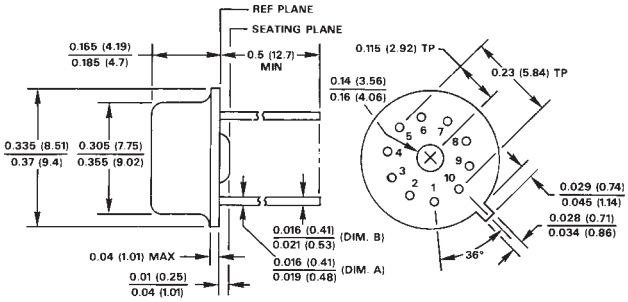
Since the output will be near +10 V, it should be ac-coupled for this adjustment. The increase in noise level and reduction in bandwidth preclude operation much beyond a ratio of 100 to 1.

*See the AD535 data sheet for more details.

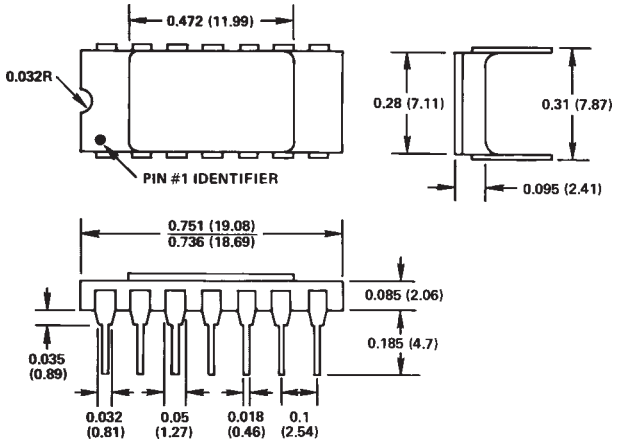
OUTLINE DIMENSIONS

Dimensions shown in inches and (mm).

H-Package TO-100



D-Package TO-116



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